

Abstract Submitted
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Monitoring GaAs photocathode heat cleaning temperature¹

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University of Nebraska- Lincoln — Before a GaAs photocathode can be “activated”
to achieve a negative electron affinity condition, the GaAs crystal must be cleaned.
This is most commonly done by ohmic, radiative, or electron bombardment heating.
We report a new technique to monitor the temperature of heated GaAs photocath-
odes by observation with a camera. The method is robust and yields the same
temperatures for different GaAs samples heated using different methods in different
mounting configurations.

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